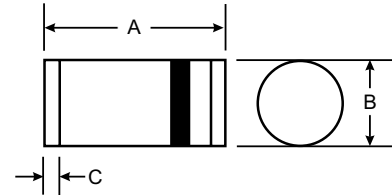


VOLTAGE RANGE: 50 - 400V
CURRENT: 1.0 A



Features

- High current capability
- High surge current capability
- High reliability
- Low reverse current
- Low forward voltage drop
- Super fast recovery time

Mechanical Data

- Case: DO-213AB/LL41
- Terminals: Plated terminals, solderable per MIL-STD-750, Method 2026
- Mounting Position: Any
- Weight: 0.116 ounce, 0.0046 gram



LL41/ DO-213AB		
Dim	Min	Max
A	4.80	5.20
B	2.40	2.60
C	0.55 Nominal	
All Dimensions in mm		

Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	EGL41A	EGL41B	EGL41C	EGL41D	EGL41F	EGL41G	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	Volts
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	Volts
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	Volts
Maximum average forward rectified current at $T_T=75^\circ\text{C}$	$I_{(AV)}$	1.0						Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30.0						Amps
Maximum instantaneous forward voltage at 1.0A	V_F	1.0			1.25			Volts
Maximum DC reverse current at rated DC blocking voltage	I_R	$T_A=25^\circ\text{C}$ 5.0			$T_A=125^\circ\text{C}$ 50.0			μA
Maximum reverse recovery time (NOTE 1)	t_{rr}	50.0						ns
Typical junction capacitance (NOTE 2)	C_J	20.0			14.0			pF
Maximum thermal resistance (NOTE 3) (NOTE 4)	$R_{\theta JA}$ $R_{\theta JT}$	60.0 30.0						$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +175						$^\circ\text{C}$

NOTES:

- (1) Reverse recovery test conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{rr}=0.25\text{A}$
- (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
- (3) Thermal resistance from junction to ambient, 0.24 x 0.24" (6.0 x 6.0mm) copper pads to each terminal
- (4) Thermal resistance from junction to terminal, 0.24 x 0.24" (6.0 x 6.0mm) copper pads to each terminal

